

LFTVS10-1F3

Transil™, transient voltage suppressor

Features

- Transient voltage suppressor
- Electrostatic discharge protection
- Electrical overstress protection
- Unidirectional device
- Low clamping factor V_{CL}/V_{BR}
- Fast response time
- Very thin package: 0.605 mm
- RoHS compliant

Complies with the following standards:

- IEC 61000-4-2 level 4
 - ± 15 kV (air discharge)
 - ± 8 kV (contact discharge)

Description

The LFTVS10-1F3 is a single line diode designed specifically for the protection of integrated circuits in portable equipment and miniaturized electronic devices subject to ESD and EOS transient overvoltages.

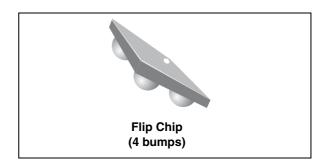


Figure 1. Pin configuration (bump side)

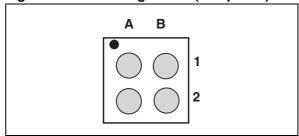
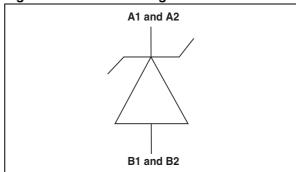


Figure 2. Device configuration



TM: Transil is a trademark of STMicroelectronics

Characteristics LFTVS10-1F3

1 Characteristics

Table 1. Absolute maximum ratings ($T_{amb} = 25$ °C)

Symbol	Parameter	Test condition	Value	Unit
D	Peak pulse power dissipation (10/1000 µs pulse)	T _i initial = T _{amb}	44	w
P _{PP}	Peak pulse power dissipation (8/20 µs pulse)	i jilililai = Tamb	350	
I _{FSM}	Non repetitive surge peak forward current	t _p = 10 ms T _j initial = T _{amb}	11	Α
T _{stg}	Storage temperature range		-55 to +150	°C
T _j	Maximum operating junction temperature		125	°C

Table 2. Electrical characteristics ($T_{amb} = 25$ °C)

Symbol	Parameter		¹ ↑		
V _{BR}	Breakdown voltage				
I _{RM}	Leakage current @ V _{RM}		l _F		
V _{RM}	Stand-off voltage	1			
V _{CL}	Clamping voltage	V _{CL} V	BR V _{RM}	J√V _F	
R _d	Dynamic impedance			I _{RM}	→ V
I _{PP}	Peak pulse current				
αΤ	Voltage temperature coefficient		Slope = 1/Rd	_	
V _F	Forward voltage drop	Ţ		Ірр	
Symbol	Test conditions	Min.	Тур.	Max.	Unit
V_{BR}	I _R = 15 mA	10			V
I _{RM}	V _{RM} = 8 V			0.5	μΑ
V _{CL}	I _{PP} = 1 A ⁽¹⁾			13	V
V _F	I _F = 850 mA ⁽²⁾			1.05	V
αΤ				8	10 ⁻⁴ / °C
C _{line}	$V_R = 0 \text{ V}, V_{OSC} = 30 \text{ mV}, F = 1 \text{ MHz}$		200		pF

^{1. 8 / 20} µs pulse waveform

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^{2.} DC current not recommended for more than 5 s. Even if diode failure mode is short circuit the bumps could exceed melting temperature and the component disassembled from the board.

LFTVS10-1F3 Characteristics

Figure 3. Relative variation of peak pulse power versus initial junction temperature

Figure 4. Peak pulse power versus exponential pulse duration (typical value)

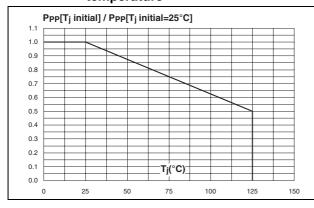
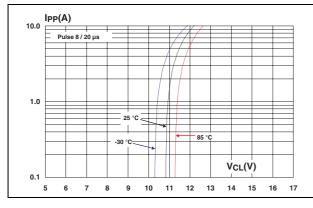


Figure 5. Clamping voltage versus peak pulse current (typical values)

Figure 6. Relative variation of leakage current versus junction temperature (typical values)



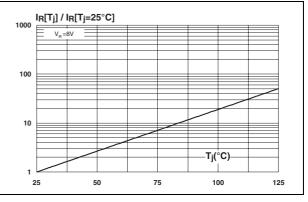
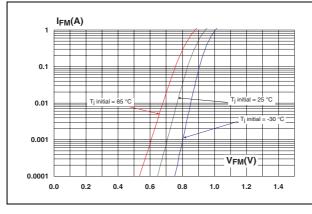
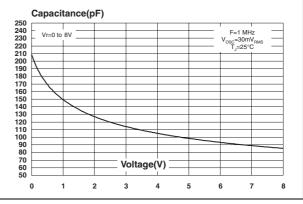


Figure 7. Forward voltage drop versus peak forward current (typical values)

Figure 8. Junction capacitance versus line voltage (typical values)





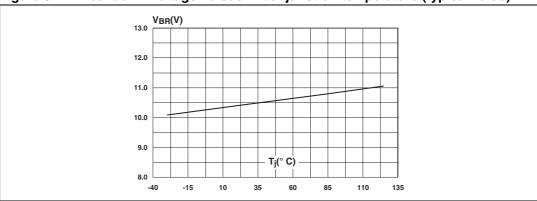
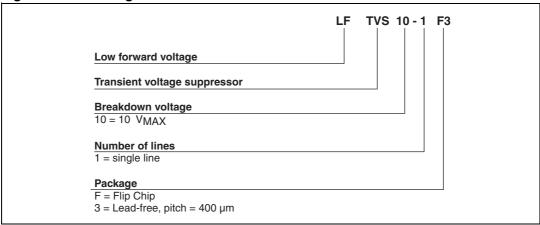


Figure 9. Breakdown voltage versus initial junction temperature (typical value)

2 Ordering information scheme

Figure 10. Ordering information scheme



LFTVS10-1F3 **Package information**

3 **Package information**

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at www.st.com.

Figure 11. Flip Chip dimensions

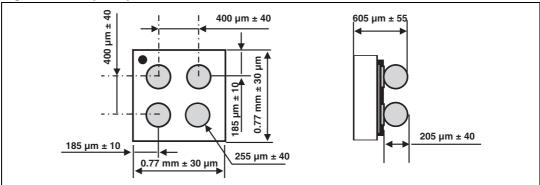


Figure 12. Footprint recommendations

Figure 13. Marking xx = marking z = manufacturing location Copper pad Diameter: 220 µm recommended yww = datecode (y = year 260 µm maximum Solder mask opening: XXZ 300 µm minimum y w w Solder stencil opening: 220 µm recommended

Ordering information LFTVS10-1F3

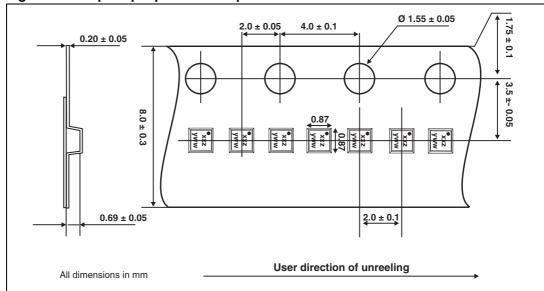


Figure 14. Flip Chip tape and reel specifications

Note:

More information is available in the application notes:

AN2348: "400 µm flip chip: Package description and recommendations for use"

AN1751: "EMI Filters: Recommendations and measurements"

4 Ordering information

Table 3. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
LFTVS10-1F3	EN	Flip Chip	0.86 mg	10 000	Tape and reel (7")

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
21-Nov-2008	1	Initial release.

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